

2N3219 Transistors

Si PNP Lo-Pwr BJT

Military/High-Rel N

$V_{(BR)CEO}$ (V) 35

$V_{(BR)CBO}$ (V) 40

I_C Max. (A) 100m

Absolute Max. Power Diss. (W) 400m

Maximum Operating Temp (θ_C) 175 \circ

I_{CBO} Max. (A) 1.0n

@ V_{CBO} (V) (Test Condition)

$V_{(CE)sat}$ Max. (V)

@ I_C (A) (Test Condition)

@ I_B (A) (Test Condition)

h_{FE} Min. Current gain.

h_{FE} Max. Current gain.

@ I_C (A) (Test Condition)

@ V_{CE} (V) (Test Condition)

f_T Min. (Hz) Transition Freq 3.0M

@ I_C (A) (Test Condition)

@ V_{CE} (V) (Test Condition)

$C_{(obo)}$ (Max) (F) 14p

@ V_{CB} (V) (Test Condition)

@Freq. (Hz) (Test Condition)